



2SA2022/2SC5610

DC/DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, strobos.

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- High allowable power dissipation.

Specifications

() : 2SA2022

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-50)60	V
Collector-to-Emitter Voltage	V_{CE0}		(-50)	V
Emitter-to-Base Voltage	V_{EB0}		(-6)	V
Collector Current	I_C		(-7)	A
Collector Current (Pulse)	I_{CP}		(-10)	A
Base Current	I_B		(-1.2)	A
Collector Dissipation	P_C		2	W
		$T_c=25^\circ\text{C}$	18	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)2\text{V}, I_C=(-)1\text{A}$	150		300	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)500\text{mA}$		(290)		MHz
				330		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(50)28		pF

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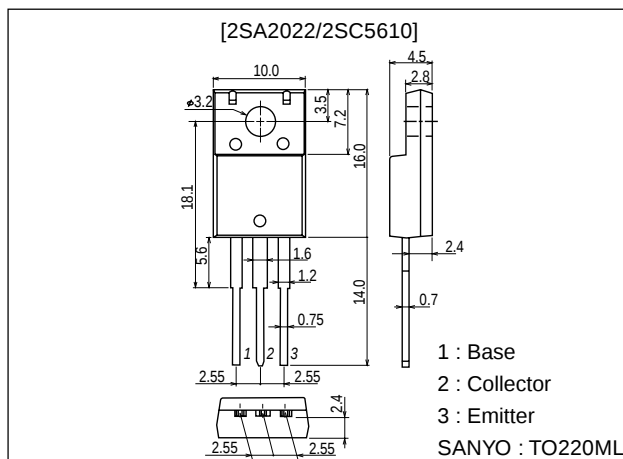
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21000TS (KOTO) TA-2470 No.6367-1/5

Package Dimensions

unit:mm

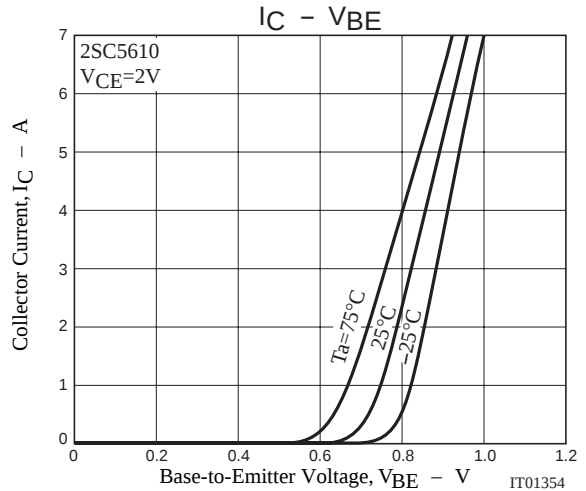
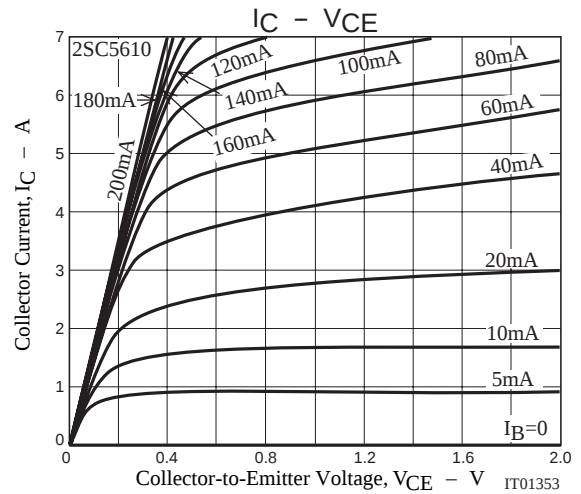
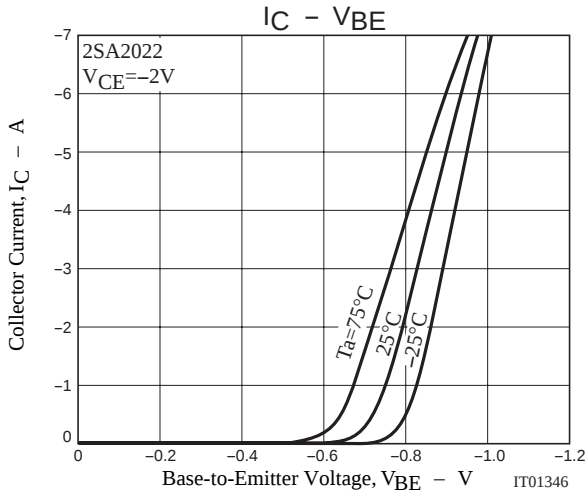
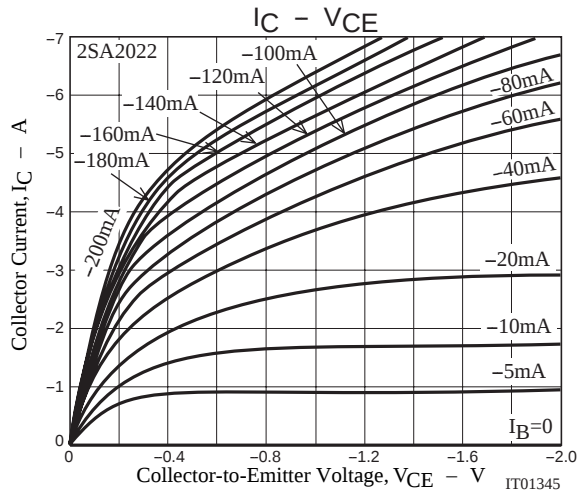
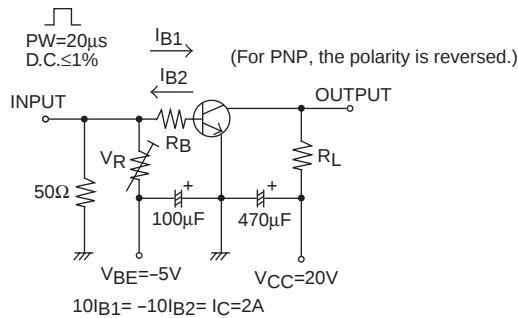
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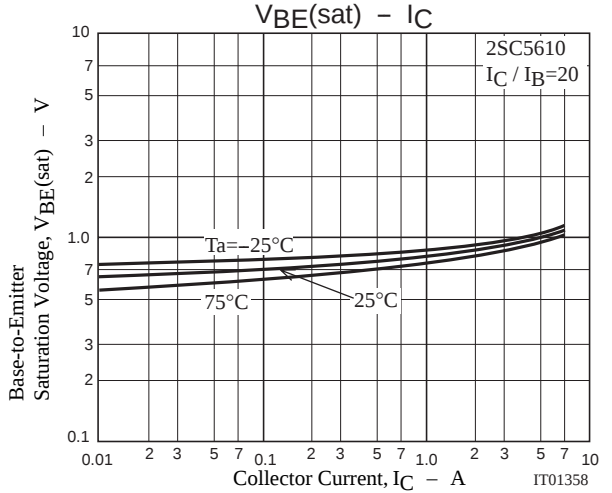
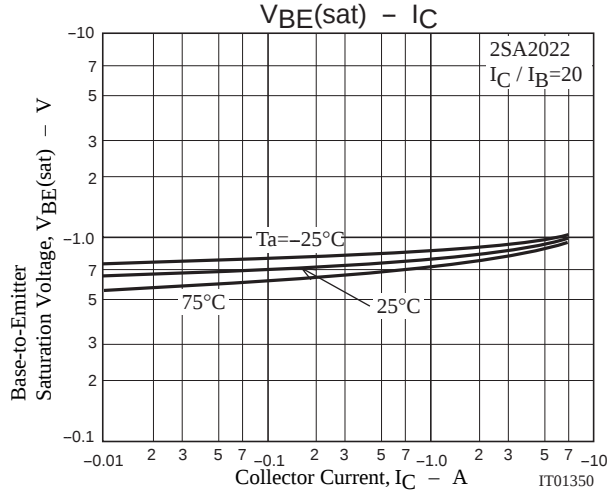
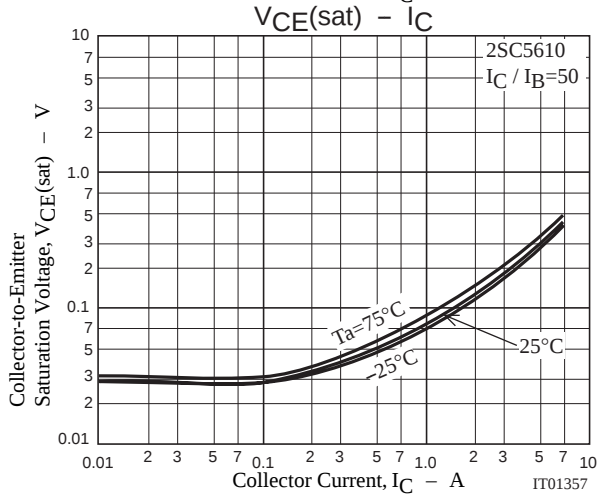
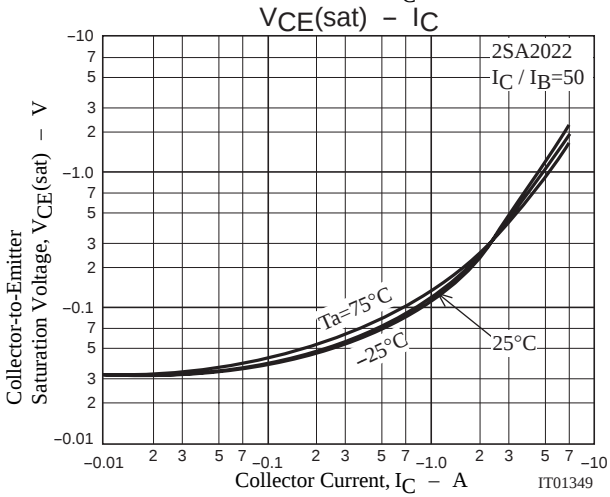
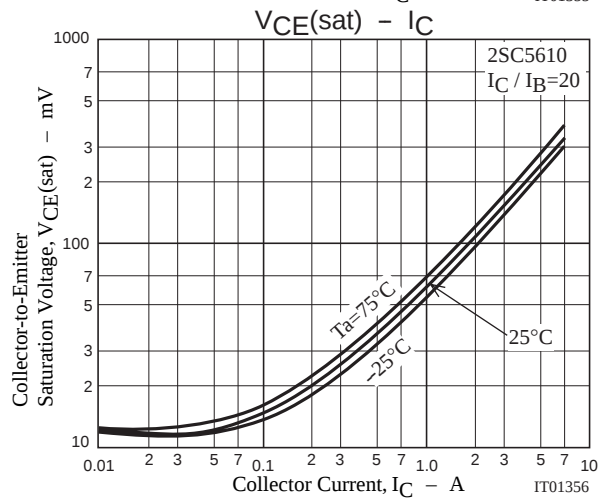
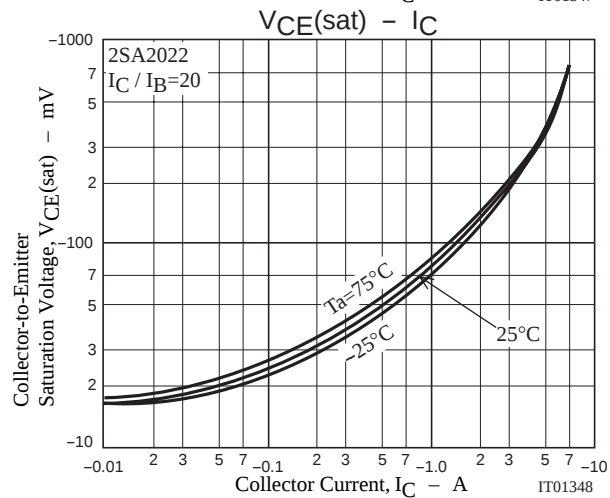
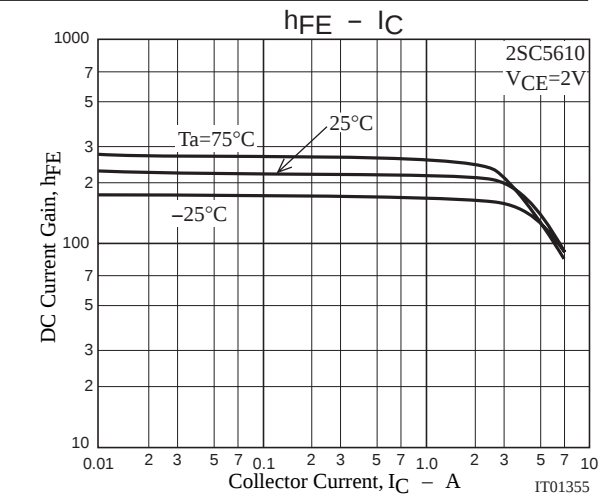
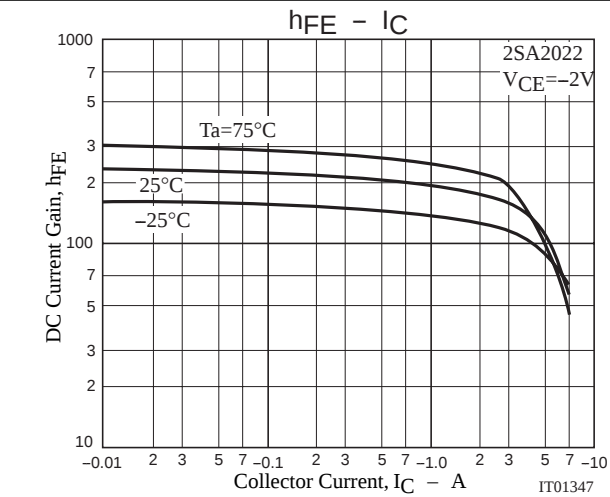


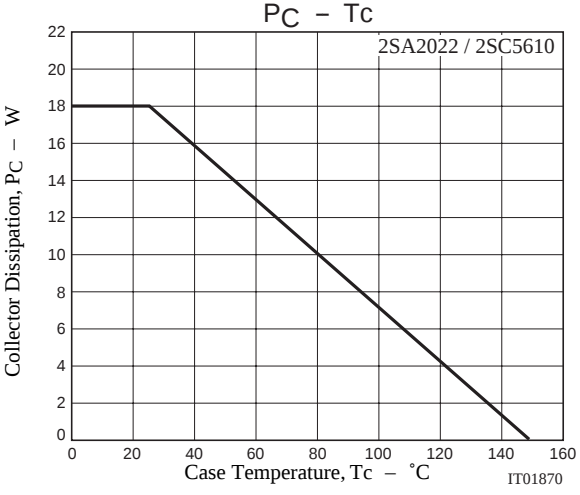
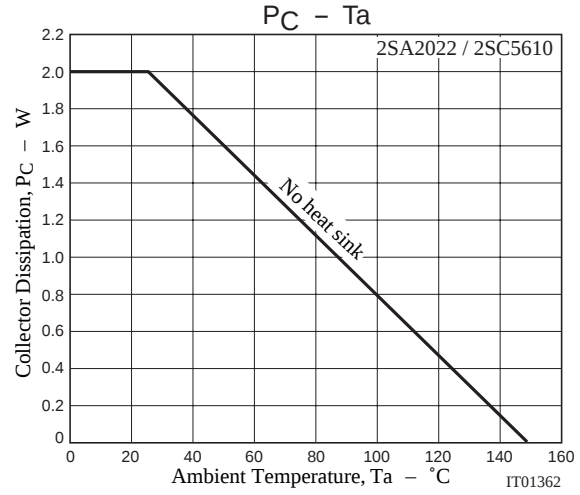
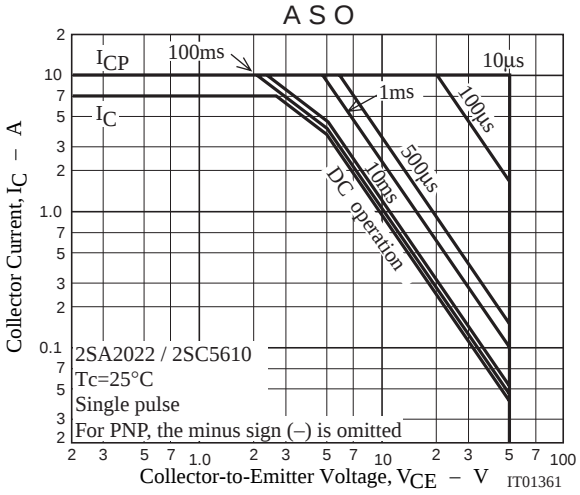
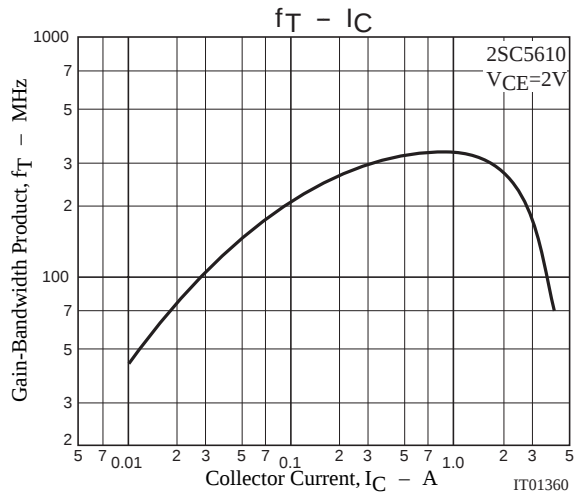
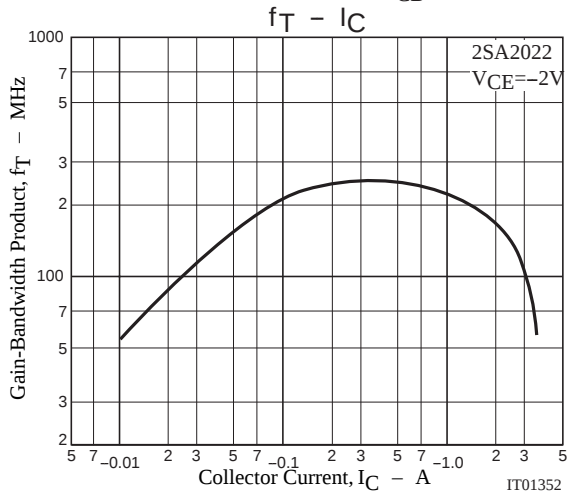
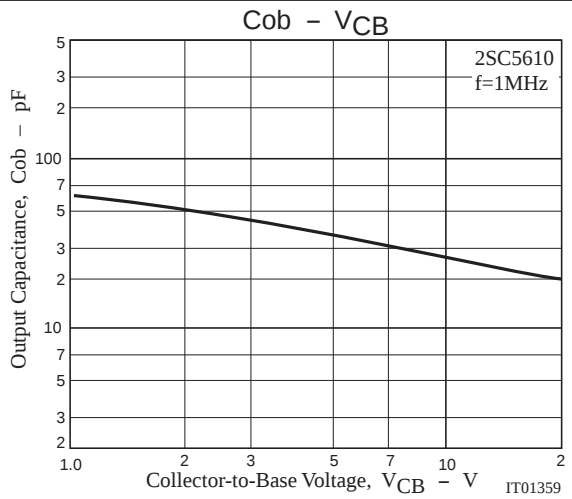
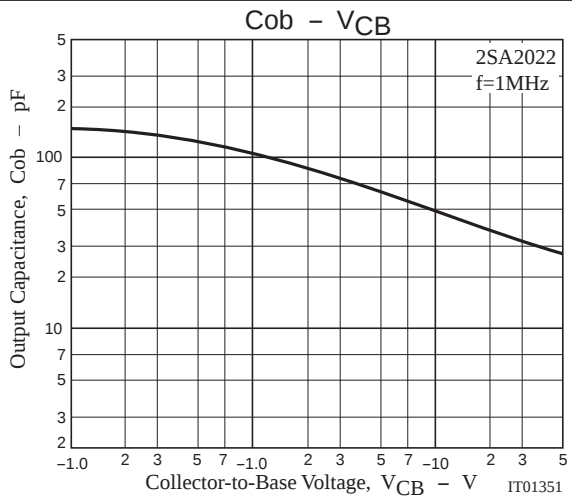
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2.5A, I_B=(-)125mA$		(-150)	(-300)	mV
				130	260	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2.5A, I_B=(-)125mA$		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-50)			V
			60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		30		ns
Storage Time	t_{stg}	See specified Test Circuit		(250)		ns
				300		ns
Fall Time	t_f	See specified Test Circuit		15		ns

Switching Time Test Circuit







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